XBS104V14

Schottky Barrier Diode, 1A, 40V Type

FEATURES

Forward Voltage	: V _F =0.365V (TYP.)
Forward Current	: I _{F(AV)} =1A
Repetitive Peak Reverse Voltage	: V _{RM} =40V

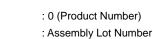
ABSOLUTE MAXIMUM RATINGS

			Ta=25			
PARAMETER	RAMETER SYMBOL		UNIT			
Repetitive Peak Reverse Voltage	Vrm	Vrm 40				
Reverse Voltage (DC)	Vr	40	V			
Forward Current (Average)	IF(AV)	1	А			
Non Continuous	IFSM	20	А			
Forward Surge Current ^{*1}	IFSM	20				
Junction Temperature	Tj	125				
Storage Temperature Range	Tstg	-55 ~ +150				

*1: Non continuous high amplitude 60Hz half-sine wave.

* When the IC is operated continuously under high load conditions such as high temperature, high current and high voltage, it may have the case that reliability reduces drastically even if under the absolute maximum ratings. Adequate "Derating" should be taken into consideration while designing.





PRODUCT NAME

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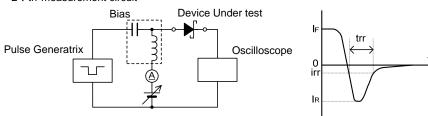
PRODUCT NAME	DEVICE ORIENTATION	
XBS104V14	R : Embossed tape, standard feed	

Please put the device orientation type "R".

ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN.	TYP.	MAX.	UNIT
Forward Voltage	VF1	I _F =100mA	-	0.23	0.315	V
	VF2	I _F =500mA	-	0.30	0.385	V
	VF3	I _F =1A	-	0.365	0.41	V
Reverse Current	lr	V _R =40V	-	0.25	2	mA
Inter-Terminal Capacity	Ct	V _R =1V , f=1MHz	-	150	-	pF
Reverse Recovery Time ^{*2}	trr	I _F =I _R =10mA , irr=1mA	-	41	-	ns

*2 : trr measurement circuit

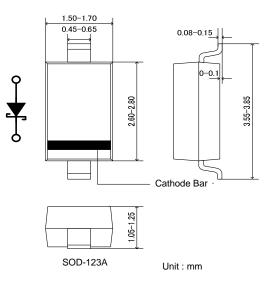


APPLICATIONS

Rectification

Protection against reverse connection of battery

PACKAGING INFORMATION



Ta=25

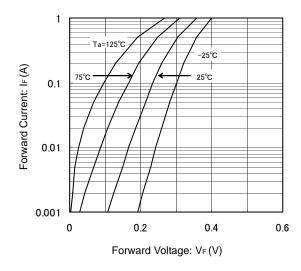


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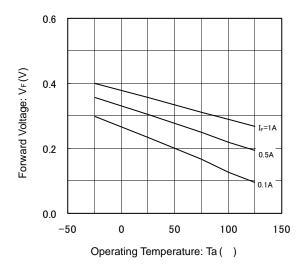
TYPICAL PERFORMANCE CHARACTERISTICS

(1) Forward Current vs. Forward Voltage

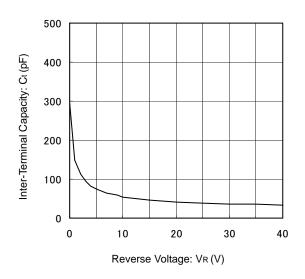
(2) Reverse Current vs. Reverse Voltage

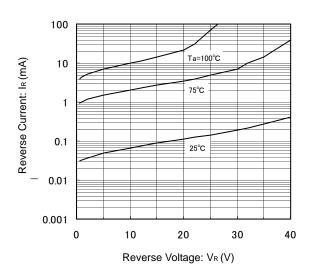


(3) Forward Voltage vs. Operating Temperature

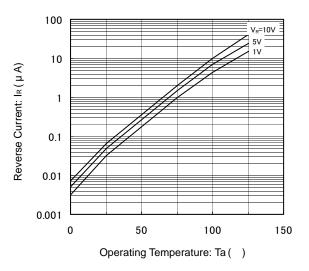


(5) Inter-Terminal Capacity vs. Reverse Voltage

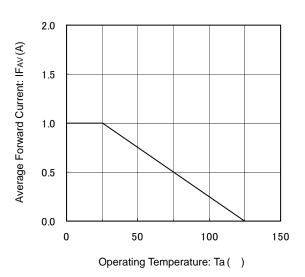




(4) Reverse Current vs. Operating Temperature



(6) Average Forward Current vs. Operating Temperature



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